

## SAM<sup>TM</sup> Data Sheet SAM-1064-20-30ps-x, $\lambda$ = 1064 nm

 $\lambda = 1064$  nm Laser wavelength

High reflection band  $\lambda = 1020 ... 1100 nm$ 

Absorbance  $A_0 = 20 \%$  $\Delta R = 15 \%$ Modulation depth  $A_{ns} = 5 \%$ Non-saturable loss

 $\Phi_{\text{sat}} = 18 \, \mu \text{J/cm}^2$ Saturation fluence

Relaxation time constant  $\tau \sim 30 \text{ ps}$ 

 $\Phi = 2 \text{ mJ/cm}^2$ Damage threshold

4.0 mm x 4.0 mm; other dimensions on request Chip area

Chip thickness 450 µm

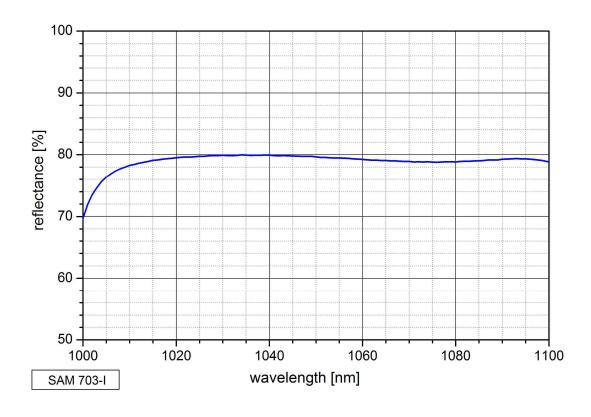
Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

unmounted  $\mathbf{x} = 0$ glued on a gold plated Cu-cylinder with 12.7 mm  $\varnothing$ x = 12.7 gx = 25.4 gglued on a gold plated Cu-cylinder with 25.4 mm Ø soldered on a gold plated Cu-cylinder with 12.7 mm  $\varnothing$ x = 12.7 s

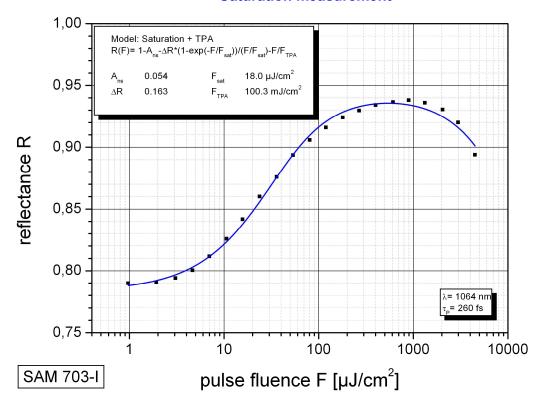
soldered on a gold plated Cu-cylinder with 25.4 mm  $\varnothing$ x = 25.4 sx = FCmounted on a 1 m monomode fiber cable with FC connector

## Low intensity spectral reflectance





## **Saturation measurement**



## **Pump-probe measurement**

